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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/770,700	02/03/2004	Tetsuo Yamada	1034-04	1306
35811	7590 03/30/2005		EXAMINER	
IP GROUP OF DLA PIPER RUDNICK GRAY CARY US LLP			KOSLOW, CAROL M	
SUITE 4900	.1 51		ART UNIT	PAPER NUMBER
PHILADELPHIA, PA 19103			1755	
•			DATE MAILED: 03/30/2005	5

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)					
Office Action Summary	10/770,700	YAMADA ET AL.					
Office Action Summary	Examiner	Art Unit					
The MAILING DATE of this account of the same	C. Melissa Koslow	1755					
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence ad	iaress				
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1: after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tim within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from cause the application to become ABANDONEI	nely filed s will be considered time the mailing date of this c O (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on							
	action is non-final.						
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
 4) ☐ Claim(s) 1-16 is/are pending in the application. 4a) Of the above claim(s) is/are withdraw 5) ☐ Claim(s) 7-12 is/are allowed. 6) ☐ Claim(s) 1, 3-6, 13, 15 and 16 is/are rejected. 7) ☐ Claim(s) 2 and 14 is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o 	vn from consideration.						
Application Papers							
9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on 03 February 2004 is/are Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Ex	e: a) accepted or b) objected drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	37 CFR 1.85(a). ected to. See 37 C	FR 1.121(d).				
Priority under 35 U.S.C. § 119							
a) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Application ity documents have been received (PCT Rule 17.2(a)).	on No d in this National	Stage				
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 4/30/04, 2/3/04	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal Pa	te	D-152)				

Application/Control Number: 10/770,700

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The Japanese references cited in the information disclosure statement of 3 February 2004 were considered with respect to the explanation of these references in the specification.

EP 1,278,250 cited in the information disclosure statement of 30 April 2004 was considered with respect to the provided English abstract.

Claim 1 is objected to because of the following informalities: The format of this claim makes it difficult to understand. It is suggested to rewrite the claim so it is clear that the percentages in paragraph 7 refer to the –sialon content. Appropriate correction is required.

Claim 13 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

These claims are improperly dependent on claims 7 and 8 since the nitrogen gas atmosphere in this claim is different from the nitrogen containing inert gas atmosphere.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1, 3-5, 15 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. patent 6,657,379.

This reference teaches a white light emitting device comprising a blue emitting light emitting diode and a transparent medium comprising a sialon based phosphor, which has a medium particle size in the range of 0.5-5 microns. The taught sialon based phosphor has the formula $M_{(p-0.04)/2}Si_{12-p-q}Al_{p+q}O_qN_{16-q}:0.04Eu^{2+}$, where p is 0-2.5, q is 0.5-3 and M can be Ca. This formula

overlaps the claimed formula. Product claims with numerical ranges which overlap prior art ranges were held to have been obvious under 35 USC 103. *In re Wertheim* 191 USPQ 90 (CCPA 1976); *In re Malagari* 182 USPQ 549 (CCPA 1974); *In re Fields* 134 USPQ 242 (CCPA 1962); *In re Nehrenberg* 126 USPQ 383 (CCPA 1960). This formula shows that the phosphor is composed of 100% α-sialon. Column 5, line 1 teaches to use high purity materials, which suggests that the total amount of metal impurities that should as low as possible, which would overlap the claimed ranges. The reference suggests the claimed phosphor and device.

Claim 6 is rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. patent 6,657,379 in view of U.S. patent 6,066,861.

As discussed above, U.S. patent 6,657,379 suggests the claimed phosphor and device. It does not teach the maximum particle size of the phosphor used in the taught device. U.S. patent 6,066,861teaches the maximum size should be 20 microns to ensure the phosphor composition has long term stability. Thus one of ordinary skill in the art would have found it obvious to limit the maximum phosphor particle size to 20 microns in the device of U.S. patent 6,657,379 for the reasons in U.S. patent 6,066,861. The references suggests the claimed phosphor.

Claims 7-12 are allowable over the cited art of record.

Claims 2 and 14 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claim 13 would be allowable if rewritten to overcome the rejection(s) under 35 U.S.C. 112, second paragraph, set forth in this Office action and to include all of the limitations of the base claim and any intervening claims.

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There is no teaching or suggestion in the cited art of record of an -sialon phosphor doped with Ce, Pr or La, and of the processes of claims 7-14.

U.S. patent 4,845,059 is cited as of interest since it teaches a similar process as that claimed, but it does not teach or suggest the claimed silicon source. The reference teaches amorphous silicon nitride that does not contain the required oxygen content. U.S. patent 6,657,379 it teaches a similar process as that claimed, but it does not teach or suggest the claimed calcium source or silicon source. The taught calcium nitride is not a substance that will thermally decompose to form CaO and the taught silicon nitride is not indicated as amorphous and containing 1-5 wt% oxygen.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Melissa Koslow whose telephone number is (571) 272-1371. The examiner can normally be reached on Monday-Friday from 8:00 AM to 3:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Jerry Lorengo, can be reached at (571) 272-1233.

The fax number for all official communications is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

cmk March 25, 2005 C. Melissa Koslow Primary Examiner Tech. Center 1700